Nonmonotonic charge occupation in double dots

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We study the occupation of two electrostatically-coupled single-level quantum dots with spinless electrons as a function of gate voltage. We hile the total occupation of the double-dot system varies monotonically with gate voltage, we predict that the competition between tunneling and Coulomb interaction can give rise to a nonmonotonic lling of the individual quantum dots. This nonmonotonicity is a signature of the correlated nature of the many-body wavefunction in the reduced Hilbert space of the dots. We identify two mechanisms for this nonmonotonic behavior, which are associated with changes in the spectral weights and the positions, respectively, of the excitation spectra of the individual quantum dots. An experimental setup to test these predictions is proposed.

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Introduction. { Quantum dots coupled to an electron reservoir can be lled with electrons one by one in a controlled way. With increasing gate voltage, the number of electrons on the dot increases in a step-like m anner. As long as Coulom b interaction among the dot electrons is negligible, the dot levels are led independently from each other. However, small sem iconductor quantum dots are usually subject to strong Coulomb interaction: charging energy gives rise to extended plateaus of (alm ost) xed dot charge as a function of gate voltage. The aim of the present paper is to demonstrate that m ore dram atic signatures of Coulomb correlations can be found in studying the lling of the individual levels in the quantum dot. W hile the total occupation of the dot rem ains a monotonic function of the gate voltage, we predict that, under circum stances specied below, the individual levels are led in a nonmonotonic way. The physics proposed here enables one to observe non-trivial many-body correlations in a particularly simple (e ective) 4-dim ensional Hilbert space.

To illustrate the signature and mechanisms of the non-monotonic lling, we consider the simplest possible model system which allows for a separate access to the individual level occupation: two electrostatically-coupled single-level quantum dots with spinless electrons, see Fig. 1. The double dot is equivalent to a single quantum dot accommodating two levels. The advantage of the double-dot setup lies in the possibility to read out separately each dot's occupation by electrostatically-coupled quantum point contacts. This kind of charge sensing has been experimentally demonstrated for single [1] and double dots [2] recently. The quantum dots are tunnel coupled to one common or to two separate electron reservoirs.

We model the double-dot system with the standard tunnel H am iltonian H = H $_{\rm dot1}$ + H $_{\rm dot2}$ + H $_{\rm ch}$ + H $_{\rm lead1}$ + H $_{\rm lead2}$ + H $_{\rm T}$;1 + H $_{\rm T}$;2. Quantum dot i = 1;2, described by H $_{\rm dot;i}$ = $_{\rm i}c_{\rm i}^{\rm y}c_{\rm i}$, accommodates a level with energy $_{\rm i}$, measured relative to the Fermienergy in the leads. The level energies can be tuned by the gate

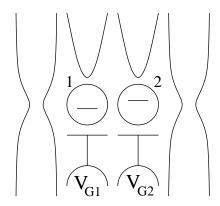


FIG. 1: Two electrostatically-coupled single-level quantum dots are attached to electron reservoirs and gated by gate electrodes. The individual occupation is determined by adjacent quantum point contacts.

electrodes. W ithout loss of generality, we always assume $_2$ $_1$. The charging energy is accounted for by H $_{ch}$ = U $_{n_1n_2}$. Each dot is coupled to an electron reservoir [3], H $_{lead;i}$ = $_{k}$ $_{ki}a_{ki}^{\gamma}a_{ki}$. Tunneling is modeled by H $_{T;i}$ = $_{k}$ $_{t_i}c_i^{\gamma}a_{ki}$ + h x: , where we assume the tunnel matrix elements to be energy independent. The tunnel coupling introduces a line width $_{i}$ = 2 $_{t_i}$ $_{i}$, where $_{i}$ is the density of states of lead $_{i}$ at the Fermi energy.

There are four possible states for the double-dot system: the double dot being empty (= 0), singly (= 1;2), or doubly (= d) occupied. The corresponding energies are E [4]. To address the question of how the occupations $\ln_1 i$ and $\ln_2 i$ of the dots vary as both levels $_1$ and $_2$ are simultaneously pulled down, we keep the bare level separation = $_2$ $_1$ xed. The fact that tunneling does not commute with the kinetic and charging terms is essential for the physics outlined below.

R egim es. { We begin with identifying the regime at which a nonmonotonic lling of the individual dots are expected. Consider rst U=0. The spectral density of dot i is a Lorentzian centered around $_{\rm i}$ with a width

 $_{\rm i}$. As $_{\rm i}$ crosses the Ferm i energy of the lead, the occupation ${\rm ln}_{\rm i}$ i of level i changes from 0 to 1. The width of this transition is governed by m axf $_{\rm i}$; $k_{\rm B}$ T g. It is obvious that in this case the occupation of each level is a monotonic function of the gate voltage. We, thus, turn our attention to the ${\rm lim}$ it U maxf; ${\rm i}k_{\rm B}$ T g.

For tem peratures larger than the level broadening, $k_B\,T$, the in uence of the tunnel couplings on the occupations is negligible and the double-dot system is led according to the Boltzm ann factors $exp\,($ $E^{(0)}=k_B\,T\,)$ of the corresponding bare energies $E^{(0)}$ with $_i=E_{i}^{(0)}$ $E_0^{(0)}$ and $U=E_d^{(0)}$ $E_1^{(0)}$ $E_2^{(0)}+E_0^{(0)}$. Now, the occupations of the two dots are correlated due to charging energy, hn_1n_2i $hn_1ihn_2i<0$, but the individual dot occupations hn_ii are still found to depend monotonically on the gate voltage. Therefore, we require & $k_B\,T$.

If the level separation is small as compared to either level width or temperature, maxfk_B T; g , then the double dot will be led in a sym metric way, $\ln_1 i$ $\ln_2 i$, which again yields a monotonic lling. This restricts the regime of interest to & & k $_B$ T .

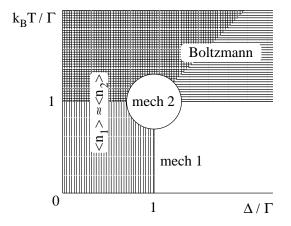


FIG. 2: For $k_B\,T$ or , the occupation of the individual dots is a monotonic function of the gate voltage. Nonmonotonicities due to mechanism 1 are strongest for $k_B\,T$, and mechanism 2 becomes excive for

 $k_B T$ and $_1 \in _2$.

M echanisms for nonmonotonicity. { We identify two dierent mechanisms by which a nonmonotonic ling of the individual levels can occur. They are both related to the Coulomb interaction, with two dierent consequences concerning the spectral density. First, as mentioned above, there is spectral weight of level 2 not only around $_2$ (describing lling or depleting of dot 2 while dot 1 is empty) but also around $_2 + U$ (describing transitions when dot 1 is lled). The total spectral weight is normalized to 1, with the relative spectral weight between the two peaks being determined by occupation of dot 1. Both peaks of level 2 are broadened by $_2$ [5], which yields a partial lling of the dot once the peak is close to the Fermienergy. As the level in dot 1 passes

through the Ferm i level and dot 1 is lled, spectral weight for the level in dot 2 is transferred from the peak around $_2$ to the one around $_2$ + U , which is further away from the Ferm i level, yielding a reduction of the partial occupation of dot 2, giving rise to a nonmonotonic lling. This mechanism will be visible for $$k_{\rm B}\,{\rm T}$$ (since otherwise the lling is dominated by thermal uctuations) and is most pronounced for $$k_{\rm B}\,{\rm T}$$.

The second mechanism is based on a renormalization of the peak positions in the spectral density due to C oulom b interaction [6]. As discussed in more detail below, tunneling in and out of dot 2 yields a renormalization of dot level 1, $_1$! $_1$. The renormalization is strongest when level 2 is close to the Ferm i energy. This renorm alization can give rise to a nonmonotonic lling of dot 2 k_BT and $hn_1i + hn_2i$ under the condition this case, both dots will be partially led once \sim_1 and ~2 are below the Fermil level. The relative occupation is approximately given by $exp(=k_BT)$. A renormalization of the level splitting then changes the relative occupation. If level 2 is close to the Ferm i level, then level 1 is strongly renormalized towards higher energies. As a consequence, the occupation of dot 2 is increased on the cost of level 1, i.e., there is a reshu ing of the relative occupation. W hen the gate voltage is increased further, the renormalization becomes weaker, and level 1 gains back some of the occupation it lost to level 2, which leads to a nonmonotonicity of hn2i. It turns out that for sym m etric coupling, $_1$ = $_2$ = , the renorm alization of the level separation is negligible in the regime k_B T since both levels are renormalized approxim ately by the sam e am ount. To get a nonm onotonic dot lling, an asym m etric coupling $_1 \in _2$ is required.

Perturbation expansion. { To substantiate the qualitative ideas outlined above, we perform a perturbation expansion of the dot occupations in the tunnelcoupling strength . For this, we employ a diagram matic im aginary-time technique that was introduced to study charge uctuations in a metallic single-electron box [7], adjusted to a two single-level-dot system. The central quantity is the partition function Z = $\exp(E)$. The corresponding e ective energies E = E $^{(0)}$ + E $^{(1)}$ + O (2) can be expanded in orders of . Evaluation of E $^{(1)}$ yields E $_0^{(1)}$ = [1(1) + 2(2)], E $_1^{(1)}$ = $[1(1) + 2(2 + U)], E_2^{(1)} = [1(1 + U) + 2(2)],$ and $E_d^{(1)} = [1(1 + U) + 2(2 + U)]$, with i(!) = $\frac{1}{2}$ In $\frac{D}{2}$ Re $\frac{1}{2}$ + $i\frac{!}{2}$, where the bandwidth D appears as a high-energy cuto at this intermediate step but drops out for all physical observables since they only depend on dierences of E 's. As a result, the dot levels are renormalized according to $\sim_i = _i + _i ^{(1)}$ with

$$_{1}^{(1)} = \frac{2}{2} Re$$
 $\frac{1}{2} + i \frac{(2 + U)}{2}$ $\frac{1}{2} + i \frac{2}{2}$; (1)

for $_2^{(1)}$ the same expression holds with 1 replaced by 2, and U remains unrenormalized in rst order in . Here, (x) is the digam ma function. From Eq. (1) we see that the renormalization of the level in dot 1 is proportional to the tunnel coupling of dot 2 (and vice versa). It is maximal when $_2$ or $_2$ + U is in resonance with the Fermi level, and vanishes in the absence of Coulomb charging.

Therm odynam ic quantities such as the occupation of the dots are obtained by adequate logarithm ic derivatives of the partition function. In particular,

$$ln_{i}i = \frac{1}{\alpha} \ln Z$$
 (2)

$$\ln_1 n_2 i = \frac{1}{e} \frac{e}{eU} \ln Z : \qquad (3)$$

The rst-order corrections of these quantities are directly obtained from

$$\frac{(\ln Z)}{k_B T}^{(1)} = \begin{array}{c} nh & \text{i} \\ & 1 & h_2 i^{(0)} \\ & h & \text{i} & \text{o} \\ & + 1 & h_1 i^{(0)} \\ & 2 (2) + h_1 i^{(0)} \\ & 2 (2 + U) \end{array}$$
(4)

plus a constant that is independent of $_1$, $_2$, and U. The set of Eqs. (2)-(4) provides the starting point for the subsequent quantitative analysis. For example, the correction to occupation of dot 2 is

where we have used $@hn_2i^{(0)} = @1 = @hn_1i^{(0)} = @2$.

R esults. { In Fig. 3 we show the dot occupations as a function of the mean level position = $(_1 + _2)$ =2 in the regime k_BT . We not nonmonotonicities which we relate to mechanism 1 discussed above. For an approximate analytical understanding of the result, we concentrate on the nonmonotonicity of $\ln_2 i$ on the right step. Since $_2 > _1$ and k_BT , we can set $\ln_2 i^{(0)} = 0$ for the whole region over which level 1 is led up, and $\ln_1 i^{(0)}$ is independent of $_2$. Nevertheless, level 2 is partially led due quantum uctuations,

$$m_2 i^{(1)}$$
 $n_1 i^{(0)} \frac{1}{2} \frac{2}{2} + m_1 i^{(0)} \frac{2}{2(2+U)}$: (6)

As level1 passes through the Fermi level, lling up quantum dot 1, the occupation of dot 2 drops from $_2$ =(2 $_2$)

down to $_2$ =[2 ($_2$ + U)]. W ithin our perturbative analysis, the width of this drop is provided by tem perature, as a broadening of level 1 due to quantum uctuations would enter in higher orders only. When going to higher order in , the width is expected to be maxfk_BT; $_1$ g. The amplitude of the drop is approximately

$$\text{ln}_2 i \frac{^2 U}{2 (+ U)}$$
: (7)

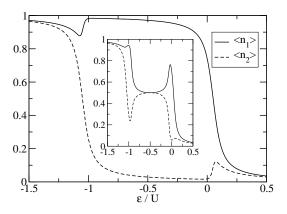


FIG. 3: Nonmonotonic dot lling due to mechanism 1. The parameters are = 0:1U, $_1$ = $_2$ = 0:1U, and $k_B\,T$ = 0:01U [8]. Inset: Result for the sym metrized Hartree approximation.

We now turn to the regime $$k_{\rm B}\,\rm T$ to discuss mechanism 2. From inspection of Eq. (1) we realize that in the given regime the renormalization of both levels is roughly the same. In order to generate a substantial renormalization of the level separation that can give rise to a nonmonotonicity, we choose dierent coupling strengths $_1$ & $_2$. In the following we discuss the case $_2$ > $_1$. The result is shown in Fig. 4. The

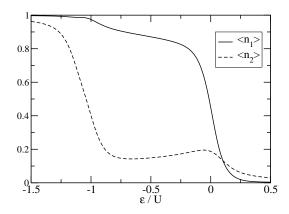


FIG. 4: Nonmonotonic dot lling due to mechanism 2 for = 0:1U , $_1$ = 0:01U , $_2$ = 0:1U , and $k_B\,T$ = 0:05U .

second line of Eq. (5) is associated with the renormalization of level 1. The renormalization (towards higher energies) is strongest when $_2$ passes through the Fermi

energy. The peak of the nonmonotonicity is, therefore, located to the left as compared to the one related with mechanism 1. The width is given by $_2$. For an estimate of its height $\,hn_2\,i$, we neglect both the possibility of the double dot being empty or doubly occupied, i.e., $hn_2\,i^{(0)}$ $\,$ exp()=[exp()+1], and we assume U $\,k_B\,T$. We nd

If we reverse the asym m etry of the coupling strengths, $_1>_2$, we nd, by using analogous argum ents as above, a nonmonotonicity of hn_1i on the left step, while hn_2i remains monotonic.

In Fig. 5 we show the correlator hn_1n_2i hn_1ihn_2i , expanded up to rst order in , for the two set of param eters chosen in Fig. 3 and Fig. 4. We not that the nonmonotonicity of the dot occupation is accompanied with an enhancement of correlation.

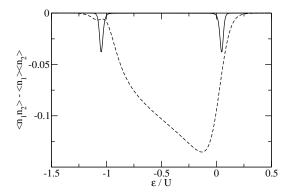


FIG. 5: Correlator h_1n_2i h_1ih_2i . The parameters are as in Fig. 3 (solid line) and Fig. 4 (dashed line).

Throughout our analysis, we assumed at bands, i.e., particle-hole-symmetric densities of states, in the leads. As a consequence, h_1i at for given $_1;_2$ is identical to 1 h_2i at U with the values of $_1$ and $_2$ being interchanged. Thus, our discussion, which was focused on the right step of h_2i holds for the left step of h_1i as well (after interchanging $_1$ \$ $_2$).

In parallel to this perturbation theory, we have performed an equation-ofm otion (EOM) analysis up to the second hierarchy solving a set of 11 coupled equations for the various G reen's functions. This approach, however, is not system atically controllable. Truncating the EOM s on the rst hierarchy results in the sym metrized Hartree approximation [9] with the G reen's function $G_{11}^{\text{ret}}(!)$ given by $G_{11}^{\text{ret}}(!)$ $= [(1 \quad h_2 i) = (! \quad 1) + h_2 i = (! \quad 1)$ U)] $= [(1 \quad h_2 i) + h_2 i = (! \quad 1)$ and $= h_2 i$ tend to be biased towards each other, but the nonmonotonicity is still observed, see the inset of Fig. 3.

Sum m ary. { In sum m ary, we predict that the \cos m - petition between tunneling and charging energy can give

rise to nonmonotonic lling of individual quantum dot levels. We identify two dierent mechanisms leading to nonmonotonicities and determine the regimes at which they occur. Based on a perturbation expansion in the tunnel couplings, we derive analytic expressions for the location and the strength of the signal.

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- [3] To describe a system in which both quantum dots are coupled to one common electron reservoir, one has to replace a_{ki} by a_k and to take into account the relative signs of the dot-level tunnelmatrix elements, making a distinction between the \in-phase" and the \out-of-phase" scenario [A.Silva, Y.Oreg, and Y.Gefen, Phys.Rev.B 66, 195316 (2002)]. On the level of calculations performed in this paper the results for all these models are identical.
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- [8] The perturbative result for $\ln_1 i$ breaks down at low temperature when $_2$ 0. Therefore, in the plot we replace $\ln_1 i^{(0)} + \ln_1 i^{(1)}$ in this region by the occupation of a noninteracting level. This does not a ect $\ln_2 i$, for which the perturbation scheme remains valid. The same procedure is done for $\ln_2 i$ around $_1$ 0.
- [9] This is to be distinguished from the self-consistent Hartree approximation, in which the bare level energies $_1$ and $_2$ are replaced by $_1$ + U $\ln_2 i$ and $_2$ + U $\ln_1 i$. Within that scheme, the spectral density for each dot has one peak that is renormalized linearly with U. In contrast, our understanding of the nonmonotonic lling at low temperature (mechanism 1) is based on the fact that the spectral density of each dot has two peaks. Mechanism 2

anism 2, on the other hand, which is elective at higher temperatures, is related to a renormalization of the level positions that depend logarithm ically on U .

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